





















Introduces

# M611x Series HCMOS/Clipped Sinewave TCXO/TCVCXO

#### Features:

- Tight stability (0.3 ppm) over wide industrial temperature range (-40 °C to +85 °C)
- 3.0 V, 3.3 V and 5.0 V versions
- Wide frequency range 8-52 MHz
- Low phase noise
- Excellent G-sensitivity performance: 1.5 ppb/G
- Tri-state function

## **Applications:**

- WiMax base stations
- Military and Avionics
- Point to point / multi-point radios
- Test and measurement and medical equipment
- WLAN
- GPS
- Frequency synthesis, frequency translation and land mobile radio

## **MtronPTI**

Corporate Headquarters 100 Douglas Avenue PO Box 630 Yankton, SD 57078-0630 1-800-762-8800 www.mtronpti.com





## **Applications Note**

#### M611x Series

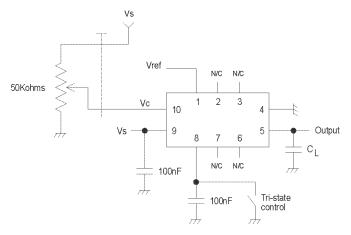
HCMOS/Clipped Sinewave TCXO/TCVCXO - 3.0/3.3/5.0 Volt - 5x7 mm

MtronPTI's M611x Series TCXO's and TCVCXO's provide design engineers with low voltage, surface mount products with extremely tight stability (to ±0.3 ppm) over temperature and time. Specially processed crystals enable the M611x to achieve consistent long-term stability and minimal frequency shift after reflow. Our processing also enables us to achieve excellent g-sensitivity (1.5 ppb/g). The low phase noise (-155 dBc/Hz at 100 kHz) makes the M611x ideal for those design engineers working on all types of systems as the reference timing source.

The M611x Series is ideally suited for a wide range of applications such as GPS, military, avionics, test and measurement, WLAN, WiMax base stations (see Fig 2.), point to point/multi-point radios, medical equipment, frequency synthesis, frequency translation and land mobile radio.

Standard output for the M611x series is HCMOS compatible or clipped sinewave and draws as little as 1.5 mA with a 3.3 volt supply at 13 MHz. This low power consumption provides an advantage over similarly specified ovenized oscillators for power-sensitive applications.

The M611x series offers  $\pm 9.2$  ppm minimum pull range with excellent tuning linearity performance for critical PLL applications. This series is available in frequencies from 8 to 52 MHz, and is offered in a ceramic surface mount platform with industry standard 5 x 7 mm footprint.





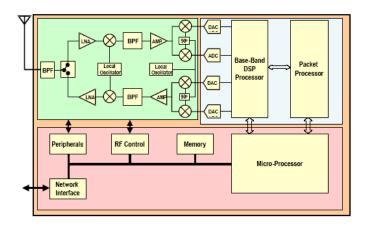


Figure 2. WiMax Subscriber Station

## **Product Specifications**

#### **Product Features:**

- Tight stability (0.3 ppm) over wide industrial temperature range (-40 °C to +85 °C)
- 3.0 V, 3.3 V and 5.0 V versions
- Wide frequency range 8-52 MHz
- Low phase noise
- Excellent G-Sensitivity performance: 1.5 ppb/G
- Tri-state Function

## **Description:**

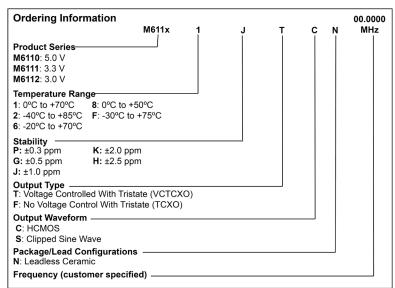
MtronPTI's M611x Series TCXO's and TCVCXO's provide design engineers with low voltage, surface mount products with extremely tight stability (to ±.3 ppm) over temperature and time. Specially processed crystals enable the M611x to achieve consistent long-term stability and minimal frequency shift after reflow. Our processing also enables us to achieve excellent g-sensitivity (1.5 ppb/g). The low phase noise (-155 dBc/Hz at 100 kHz) makes the M611x ideal for those design engineers working on all types of systems as the reference timing source.

## **Applications:**

- WiMax base stations
- · Military and avionics
- · Point to point / multi-point radios
- Test and measurement and medical equipment
- WLAN
- GPS
- Frequency synthesis, frequency translation and land mobile radio

## **Ordering Information:**

Part Number Example: M611x 1 J T C N 40.000000MHz



Part Number Example: M6111JTCN – 40.000000 MHz

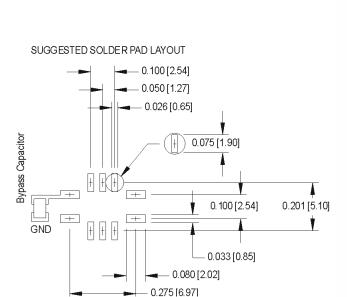
## Performance Characteristics:

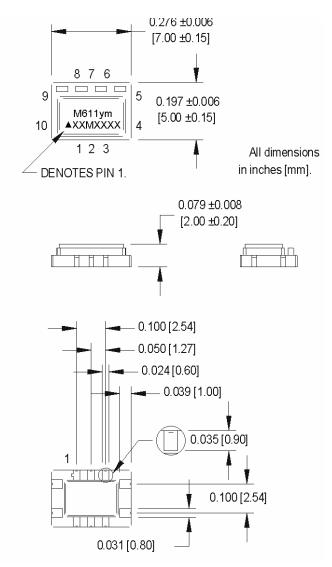
	Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions/Notes	
	Frequency Range	Fo	8		52	MHz		
	Operating Temperature	T <sub>A</sub>	-40		+85	°C	See Ordering Information	
	Storage Temperature	T <sub>STG</sub>	-55		+125	°C		
	Frequency Tolerance @ +25°C		-1.0		+1.0	ppm	For TCXO only	
	Frequency Stability						See Ordering Information	
	Stability Vs. Reflow		-1.0		+1.0	ppm		
	Frequency Vs. Supply			±0.2		ppm	For 10% supply voltage variation	
	Frequency Vs. Load			±0.2		ppm	For 10% load variation	
	Aging (First Year)		-1.0		+1.0	ppm	F <sub>0</sub> ≤ 20 MHz	
	Aging (First Year)		-2.0		+2.0	ppm	F <sub>0</sub> ≥ 20 MHz	
	Aging (10 Year)		-3.0		+3.0	ppm	F <sub>0</sub> ≤ 20 MHz (Includes first year)	
	Aging (10 Year)		-5.0		+5.0	ppm	F <sub>0</sub> ≥ 20 MHz (Includes first year)	
Ш	Supply Voltage Tolerance		-5.0		+5.0	%	See Ordering Information	
Ш	Supply Current (I <sub>D</sub> )			2.2	3.3	mA	HCMOS output at 13 MHz	
				3.5	5.0	mA	HCMOS output at 26 MHz	
				6.0	9.2	mA	HCMOS output at 52 MHz	
ဋ				1.5	2.2	mA	Clipped sinewave output at 13 MHz	
ö				1.8	2.7	mA	Clipped sinewave output at 26 MHz	
cat				3.0	4.5	mA	Clipped sinewave output at 52 MHz	
ij	Output Logic Levels	$V_{OL}$			20	%V <sub>S</sub>	$I_{OH}/I_{OL} = \pm 4 \text{ mA}, \text{ Vs} = +3.0 \text{ V}$	
be	(HCMOS)	$V_{OH}$	80			%V <sub>S</sub>	$I_{OH}/I_{OL} = \pm 4 \text{ mA}, \text{ Vs} = +3.0 \text{ V}$	
Electrical Specifications	Output Level		1.0			V <sub>pk-pk</sub>	F <sub>0</sub> <_40 MHz	
<u>  2</u>	(Clipped Sinewave)		0.8			V <sub>pk-pk</sub>	F <sub>o</sub> > 40 MHz	
ctr	Waveform Symmetry		40		60	%	Ref. to ½ V <sub>S.</sub> HCMOS only	
읣	Rise/Fall Time Output Load			15	8	ns pF	Ref. 10% to 90%. HCMOS only HCMOS output	
	Output Load			10/10		Kohm/pF	Clipped sinewave output	
Ш	Frequency Adjustment		±9.2	10/10		ppm	Over Control Voltage Range	
	Control Voltage Range	<b></b>	0.3		2.7	Volts	For $V_S = 3.0$	
Ш	Control Voltage Harige		0.3		3.0	Volts	For $V_S = 3.3$	
			0.5		4.5	Volts	For V <sub>S</sub> = 5.0	
Ш	Input Leakage Current		-50		+50	μA	Pad 10	
	Input Resistance		100			Kohm	Pad 10	
	Linearity				3	%		
	Modulation Bandwidth		2 kHz				Pad 10	
	Tristate Function (Pad 8)		70			%V <sub>S</sub>	Output enabled. Logic "1" or "Open"	
					30	%V <sub>S</sub>	Output disabled. Logic "0" or "GND"	
	Tristate Leakage Current		-100		+100	μA	Pad 8	
	Phase Noise			-95		dBc/Hz	10 Hz Offset	
	(Typical 10 MHz CMOS)			-125		dBc/Hz	100 Hz Offset	
	,			-145		dBc/Hz	1 KHz Offset	
				-152		dBc/Hz	10 KHz Offset	
				-155		dBc/Hz	100 kHz Offset	
틸								
nta	Shock	MIL-STD-2	02, Metho	d 213, Cor	100 g			
l el	Vibration	MIL-STD-2			10 g from 10 to 2000 Hz			
	Solderability	EIAJ-STD-	002					
Environmental	Package	5.0 x 7.0 x	2.0 mm, 1	0-pad SM	RoHS Compliant			
[피	Max Soldering Conditions	See solder	profile, Fig	gure 1				
닉	<del>-</del>	IOS Load – see load circuit diagram #2 Sinewaye Load – see load circuit diagram #7						

HCMOS Load – see load circuit diagram #2. Sinewave Load – see load circuit diagram #7.

#### Product Dimensions & Pinout Information:

Pin Connections								
Function	Pad							
Vref or N/C	1							
N/C	2							
N/C	3							
Ground	4							
Output	5							
N/C	6							
N/C	7							
Tristate	8							
Supply Voltage (V <sub>s</sub> )	9							
Control Voltage	10							





## Handling Information:

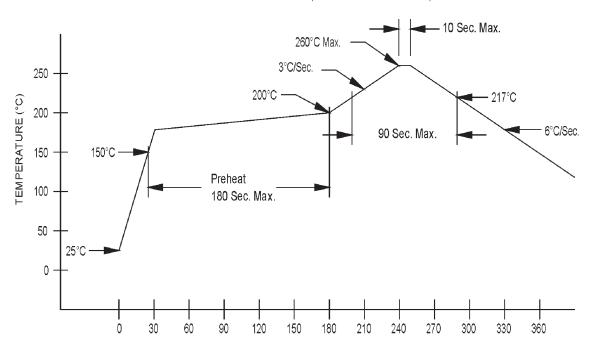
Although protection circuitry has been designed into the M611x TCXO/TCVCXO, proper precautions should be taken to avoid exposure to electrostatic discharge (ESD) during handling and mounting. MtronPTI utilizes a human-body model (HBM) and a charged-device model (CDM) for ESD-susceptibility testing and protection design evaluation. ESD voltage thresholds are dependent on the circuit parameters used to define the mode. Although no industry-wide standard has been adopted for the CDM, a standard HBM (resistance = 1500, capacitance = 100 pF) is widely used and therefore can be used for comparison purposes. The HBM ESD threshold presented here was obtained using these circuit parameters.

Model	ESD Threshold, Minimum	Unit
Human Body	1500*	V
Charged Device	1500*	V

\* MIL-STD-833D, Method 3015, Class 1

## Solder Profile:





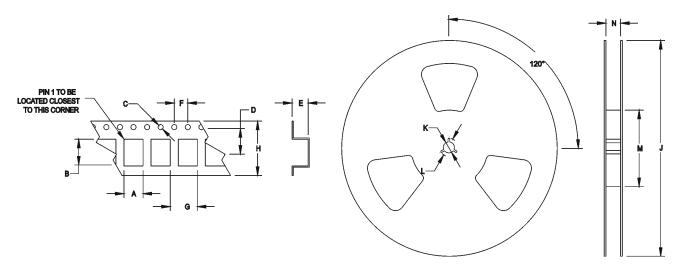
# **Quality Parameters:**

Environmental Specifications/Qualification Testing Performed on the M611x TCXO/TCVCXO									
Test	Test Method	Test Condition							
Electrical Characteristics	Internal Specification	Per Specification							
Frequency vs. Temperature	Internal Specification	Per Specification							
Mechanical Shock	MIL-STD-202, Method 213, C	100 g, 6 ms							
Vibration	MIL-STD-202, Method 201-204	10 g from 10-2000 Hz							
Thermal Cycle	MIL-STD-883, Method 1010, B	-55 Deg. C to +125 Deg. C, 15 minute Dwell, 10 cycles							
Aging	Internal Specification	168 Hours at 105 Degrees C							
Gross Leak	MIL-STD-202, Method 112	30 Second Immersion							
Fine Leak	MIL-STD-202, Method 112	Must meet 1x10 <sup>-8</sup>							
Solderability	MIL-STD-883, Method 2003	8 Hour Steam Age – Must Exhibit 95% coverage							
Resistance to Solvents	MIL-STD-883, Method 2015	Three 1 minute soaks							
Terminal Pull	MIL-STD-883, Method 2004, A	2 Pounds							
Lead Bend	MIL-STD-883, Method 2004, B1	1 Bending Cycle							
Physical Dimensions	MIL-STD-883, Method 2016	Per Specification							
Internal Visual	Internal Specification	Per Internal Specification							

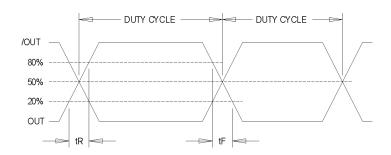
# $\textbf{M611x Series} \ \ \text{HCMOS/Clipped Sinewave TCXO/TCVCXO} - 3.0/3.3/5.0 \ \ \text{Volt} - 5x7 \ \ \text{mm}$

# Tape and Reel Specifications:

(all measurements are in mm)	Α	В	С	D	Е	F	G	Н	J	K	L	M	N
M611x	5.40	7.40	1.55	7.50	2.60	2.00	4.00	16.00	330	13.00	20.20	100	16.40



Standard Tape and Reel: 1000 parts per reel



**Output Waveform** 



#### **Yankton**

PO Box 630 Yankton, SD 57078-0630 USA Phone: 605-665-9321 Toll Free: 800-762-8800 Fax: 605-665-1709

Email: SalesYKT@mtronpti.com

#### <u>Orlando</u>

2525 Shader Rd Orlando, FL 32804 USA Phone: 407-298-2000 Fax: 407-293-2979 Email: SalesORL@mtronpti.com

#### **Connecticut**

755 Main Street Suite 2B, Building 2 Monroe, CT 06470 USA Phone: 800.762.8800 Fax: 203.452.9435 Email: MilSales@mtronpti.com

#### Santa Clara

1495 Franklin Street Santa Clara, CA 95050 USA Phone: 408.395.0700 Fax: 408.395.8074 Email: SalesCA@mtronpti.com

#### **Europe**

The Netherlands
Phone: 31-40-368-6818
Fax: 011-31-40-368-3501
Email: SalesEU@mtronpti.com

#### **Asia Pacific**

1104 Shanghai Industrial Investment Building 48-62 Hennessy Road Wanchai, Hong Kong, China Phone: 852-2866-8023 Fax: 852-2529-1822 Email: SalesHK@mtronpti.com